

## Silicon NPN Phototransistor



#### **FEATURES**

Package type: leadedPackage form: T-1

• Dimensions (in mm): Ø 3

High photo sensitivity

· High radiant sensitivity

• Suitable for visible and near infrared radiation

• Fast response times

• Angle of half sensitivity:  $\varphi = \pm 25^{\circ}$ 

 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>





BoHS

FREE

GREEN (5-2008)

#### DESCRIPTION

BPW85 is a silicon NPN phototransistor with high radiant sensitivity in clear, T-1 plastic package. It is sensitive to visible and near infrared radiation.

#### **APPLICATIONS**

Detector in electronic control and drive circuits

PRODUCT SUMMARY						
COMPONENT	I <sub>ca</sub> (mA)	φ (deg)	λ <sub>0.1</sub> (nm)			
BPW85	0.8 to 8	± 25	450 to 1080			
BPW85A	0.8 to 2.5	± 25	450 to 1080			
BPW85B	1.5 to 4	± 25	450 to 1080			
BPW85C	3 to 8	± 25	450 to 1080			

### Note

Test condition see table "Basic Characteristics"

ORDERING INFORMATION						
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM			
BPW85	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1			
BPW85A	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1			
BPW85B	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1			
BPW85C	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1			

### Note

• MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Collector emitter voltage		V <sub>CEO</sub>	70	V		
Emitter collector voltage		V <sub>ECO</sub>	5	V		
Collector current		I <sub>C</sub>	50	mA		
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	100	mA		
Power dissipation	T <sub>amb</sub> ≤ 55 °C	P <sub>V</sub>	100	mW		
Junction temperature		Tj	100	°C		
Operating temperature range		T <sub>amb</sub>	-40 to +100	°C		
Storage temperature range		T <sub>stg</sub>	-40 to +100	°C		
Soldering temperature	$t \le 3$ s, 2 mm from case	T <sub>sd</sub>	260	°C		
Thermal resistance junction/ambient	Connected with Cu wire Ø 0.14 mm <sup>2</sup>	R <sub>thJA</sub>	450	K/W		

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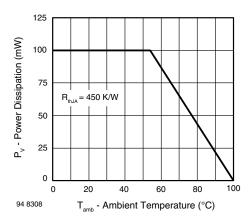


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector emitter breakdown voltage	I <sub>C</sub> = 1 mA	V <sub>(BR)CEO</sub>	70			V
Collector emitter dark current	V <sub>CE</sub> = 20 V, E = 0	I <sub>CEO</sub>		1	200	nA
Collector emitter capacitance	$V_{CE} = 5 \text{ V, f} = 1 \text{ MHz, E} = 0$	C <sub>CEO</sub>		3		pF
Angle of half sensitivity		φ		± 25		deg
Wavelength of peak sensitivity		$\lambda_{p}$		850		nm
Range of spectral bandwidth		λ <sub>0.1</sub>		450 to 1080		nm
Collector emitter saturation voltage	$E_e = 1 \text{ mW/cm}^2,  \lambda = 950 \text{ nm},$ $I_C = 0.1 \text{ mA}$	V <sub>CEsat</sub>			0.3	V
Turn-on time	$V_{S} = 5 \text{ V}, I_{C} = 5 \text{ mA}, R_{L} = 100 \Omega$	t <sub>on</sub>		2.0		μs
Turn-off time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	t <sub>off</sub>		2.3		μs
Cut-off frequency	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	f <sub>c</sub>		180		kHz

TYPE DEDICATED CHARACTERISTICS							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector light current	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm},$ $V_{CE} = 5 \text{ V}$	BPW85	I <sub>ca</sub>	0.8		8.0	mA
		BPW85A	I <sub>ca</sub>	0.8		2.5	mA
		BPW85B	I <sub>ca</sub>	1.5		4.0	mA
		BPW85C	I <sub>ca</sub>	3.0		8.0	mA

### **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

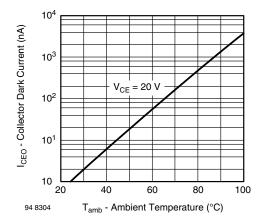


Fig. 2 - Collector Dark Current vs. Ambient Temperature

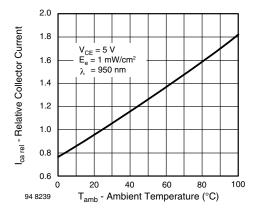


Fig. 3 - Relative Collector Current vs. Ambient Temperature

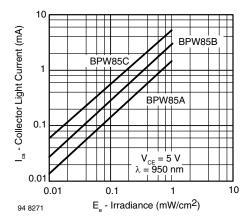


Fig. 4 - Collector Light Current vs. Irradiance

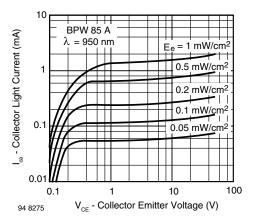


Fig. 5 - Collector Light Current vs. Collector Emitter Voltage

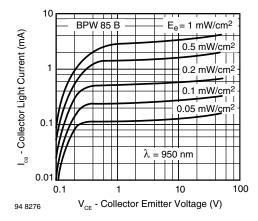


Fig. 6 - Collector Light Current vs. Collector Emitter Voltage

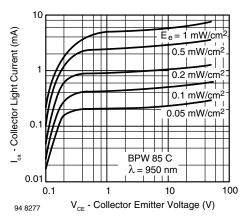


Fig. 7 - Collector Light Current vs. Collector Emitter Voltage

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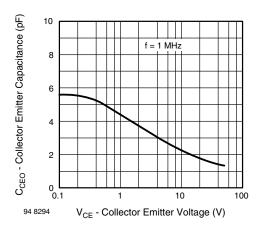


Fig. 8 - Collector Emitter Capacitance vs. Collector Emitter Voltage

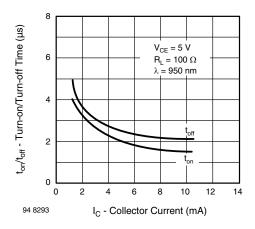


Fig. 9 - Turn-on/Turn-off Time vs. Collector Current

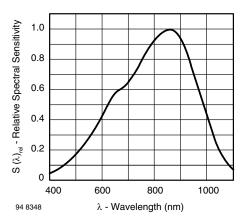


Fig. 10 - Relative Spectral Sensitivity vs. Wavelength

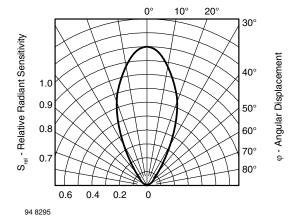
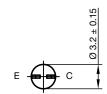
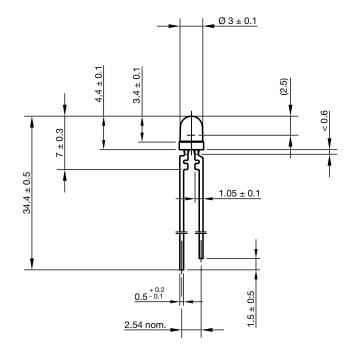
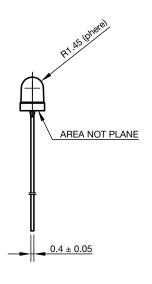


Fig. 11 - Relative Radiant Sensitivity vs. Angular Displacement

### **PACKAGE DIMENSIONS** in millimeters







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